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## Observation of large multiple scattering effects in ultrafast electron diffraction on single crystal silicon

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We report on ultrafast electron diffraction on high quality single crystal silicon. The ultrafast dynamics of the Bragg peaks exhibits a giant photo-induced response which can only be explained in the framework of dynamical diffraction theory, taking into account multiple scattering of the probing electrons in the sample. In particular, we show that lattice heating following photo-excitation can cause an unexpected increase of the Bragg peak intensities, in contradiction with the well-known Debye-Waller effect. We anticipate that multiple scattering should be systematically considered in ultrafast electron diffraction on high quality crystals as it dominates the Bragg peak dynamics. In addition, taking into account multiple scattering effects opens the way to quantitative studies of non-equilibrium dynamics of defects in quasi-perfect crystals.

#### I. INTRODUCTION

The field of ultrafast dynamics in condensed matter has been very active in the past decades. Its main motivation is to gain new insight on the complex interplay between the various degrees of freedom in materials (charge, lattice, spins) directly in the time domain. In particular, ultrafast X-ray diffraction [1, 2] and ultrafast electron diffraction (UED) [3–5] are ideal techniques for obtaining valuable information on structural dynamics at the atomic scale. The use of ultrafast electron diffraction in pump-probe experiments has proven to be very efficient for studying the dynamics of photo-induced phase transitions by measuring the relative changes of the diffraction pattern following photo-excitation [6–10]. Indeed, in the case of a structural phase transition, interpreting the dynamics of the diffraction pattern is relatively straightforward: the change in the crystal symmetry can be monitored through the appearance/disappearance of Bragg peaks [7, 10]. However, a wealth of additional information is contained in the diffraction pattern, e.g. lattice heating can be estimated through the change of the Bragg peak intensity due to the Debye-Waller effect. Quantitative analysis mostly relies on the use of kinematical diffraction theory, which assumes that the scattering potential of the crystal lattice is a small perturbation, so that the probing electrons undergo a single elastic scattering event, leading to a weak diffracted intensity compared to the incident electron beam. This theory gives satisfactory results when applied to the case of polycrystalline samples where the grain size is only a few nanometers [10, 11]. It led to quasi-direct measurements of the lattice temperature with sub-picosecond resolution in several materials [5, 11]. However, as high quality single crystal samples adapted to UED experiments are becoming available, kinematical theory does not appear sufficient to explain all experimental results. Several UED studies on high quality crystals, such as silicon [12] and graphite [13] have reported large photo-induced changes of the Bragg peak intensity that cannot be explained by kinematical theory. The authors proposed that multiple scattering of the electrons must be at play but no quantitative analysis was performed to fully confirm this hypothesis.

In electron microscopy, multiple scattering is taken into account in the framework of dynamical diffraction theory [14, 15]. In high quality crystals, multiple scattering needs to be considered due to the very high elastic scattering cross section of electrons. Despite this, little attention has been given to these effects in timeresolved electron diffraction experiments. To our knowledge, multiple scattering was considered in detailed only in [16] in a UED experiment in reflexion geometry designed to study surface dynamics. In this paper, we show that multiple scattering completely dominates the dynamics of the diffraction pattern in the commonly used transmission geometry. The experiment is performed on nano-membranes of monocrystalline silicon which is the archetypal example of the perfect single crystal. In addition, the availability of the silicon scattering potential enables a thorough and quantitative comparison between experiment and theory, leading to the unambiguous conclusion that the observed dynamics is dominated by the photo-induced changes of multiple scattering physics.

#### II. EXPERIMENTAL METHOD

The electron bunches are first generated by back-illuminating a gold photo-cathode with a  $\lambda=266\,\mathrm{nm}$ 

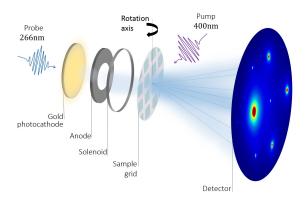


FIG. 1: Scheme of the experimental setup. The electron beam is generated on the photo-cathode by the third harmonic of the laser and accelerated in the DC gun followed by a solenoid. After a certain time delay the pump arrives on the other side of the sample. The resulting diffraction pattern is detected with an MCP and imaged onto a CCD camera.

ultrashort laser pulse of < 60 fs duration. Electrons are then accelerated in a DC gun, delivering accelerating voltages up to 100 keV, and then focused by a solenoid to a spot size of  $150 \,\mu\mathrm{m}$  Full Width Half Maximum (FWHM) at the sample position. The charge of the electron bunch beam is < 1 fC resulting in space charge dominated bunches with a transverse coherence length of  $\sim 4\,\mathrm{nm}$  and  $< 300\,\mathrm{fs}$  duration, as estimated using the GPT code [17]. An scheme of the experimental setup is shown in Fig. 1. Unless stated otherwise, the electron energy is  $45\,\mathrm{keV}$ . The silicon sample is pumped with a 35 fs pump laser pulse, with  $\lambda=400\,\mathrm{nm}$  photons. The incident fluence is  $12\pm1\,\mathrm{mJ/cm}^2$ , over a  $500\,\mu\mathrm{m}$ FWHM laser spot. The diffracted peaks are detected with a MCP detector imaged onto a CCD camera. The experiment is performed at 1 kHz repetition rate and each diffraction image is obtained by accumulating over 5000 pulses. The silicon samples were thinned out from a silicon on insulator wafer [18], resulting in a grid of  $350 \times 350 \,\mu\text{m}$  free standing nano-membranes with [001] orientation. The membrane thickness was measured using convergent beam electron diffraction [19] and estimated to be  $70 \pm 2 \,\mathrm{nm}$ .

#### III. RESULTS

We start by reviewing some properties of silicon and its expected dynamical response following photo-excitation. We measured the pump pulse absorption in the sample to be  $55 \pm 5\%$ . Thus, starting from an incident fluence of  $F_{inc} = 12\,\mathrm{mJ/cm}^2$ , the absorbed fluence is estimated at  $F_{abs} = 6.5\,\mathrm{mJ/cm}^2$ . The pump laser pulse causes the excitation of electron-hole pairs and the density of excited electrons in the conduction band is given

by:  $n_{exc}=F_{abs}/L\hbar\omega,~i.e.~n_{exc}=1.8\times10^{21}\,\mathrm{cm^{-3}}$  for our experimental parameters. Excited carriers thermalize via electron-electron scattering on the 100 fs time scale [20] and form two subsystems comprising hot electrons and holes. The electrons (holes) subsequently relax to the bottom of the conduction band (top of the valence band) through electron-phonon coupling on a picosecond timescale, causing lattice heating [11, 21]. Using ab initio calculations [22] for determining the quasiparticle density of states of the valence and conduction bands [23], as well as the specific heat  $C_p(T)$  of silicon, we were able to determine the lattice temperature after electron relaxation assuming that the number of electron-hole pairs stays constant during this part of the dynamics. This gives a lattice temperature increase of  $\Delta T = 240 \,\mathrm{K}$ . Additional delayed heating occurs via electron-hole pair recombination across the gap. At this excitation level, it is well-known that the dominant mechanism is Auger recombination [24]. The dynamics of excited carrier is governed by the following equation  $dn_{exc}/dt = -(C_e + C_h)n_{exc}^3$ , where  $C_e$  and  $C_h$ are the Auger coefficients for electron and holes respectively. Following Dziewior and Schmid [25], we used  $C_e + C_h = 3.8 \times 10^{-31} \text{ cm}^6 \text{s}^{-1}$ , and we find that 90% of the Auger recombination has occurred after 40 ps and 94% after 100 ps. Therefore, after 100 ps, we estimate a temperature increase of  $\Delta T = 460 \,\mathrm{K}$ . At this point, the system reaches a metastable state as heat diffusion occurs on the microsecond time scale for our sample geometry. In kinematical diffraction, lattice heating manifests itself by the decrease of the Bragg peak intensities according to the Debye-Waller factor:  $I_{hkl}(T) = I_{hkl}(0)e^{-2M}$ , with  $2M = \langle u^2 \rangle \Delta k_{hkl}^2$ . Here,  $\langle u^2 \rangle$  represents the rms displacement of atoms around their equilibrium position and  $\Delta k_{hkl} = 4\pi \sin \theta_{hkl}/\lambda$ , where  $\lambda$  is the electron de Broglie wavelength. Using ab initio calculations [22, 23, 26] for estimating the values of  $\langle u^2 \rangle$ , we find that the (220) peaks should all decrease by 10% after lattice heating is completed:  $I_{220}(800 \text{ K})/I_{220}(300 \text{ K}) - 1 = 0.9$ . This scenario and the use of kinematical theory to interpret the decrease of the Bragg peak intensities was validated in a UED experiment on polycrystalline silicon [11].

We now demonstrate that this interpretation does not hold in the case of high quality single crystals. Typical diffraction patterns from the silicon nano-membranes are shown in Fig. 2. In a), the electron beam is oriented so that it is parallel to the [001] direction: the diffraction pattern is symmetric and the various (220) peaks have similar intensity. The diffracted beam intensities is about one order of magnitude lower compared to the intensity of the transmitted electron beam (referred to as the 0-order beam in the following). In contrast, in b) the sample was tilted along the horizontal axis (represented by the dashed black line) so that the (2-20) peak satisfies the Bragg condition. The diffraction pattern is quite asymmetric and remarkably, the 0-order and the (2-20) peak

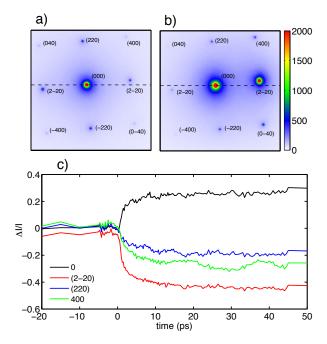


FIG. 2: a-b): Diffraction images from a [001] oriented silicon nano-membrane. a) The crystal is oriented such that the electron beam is parallel to the [001] axis. b) The crystal is tilted by the Bragg angle  $\theta_{220}=0.84^{\circ}$  such that the Bragg condition is satisfied for the (2-20) peak. c) Result of a pump-probe scan showing the relative intensity changes of various Bragg peaks  $\Delta I/I$ . The incident fluence is  $12\,\mathrm{mJ/cm^2}$ 

have similar intensities. This fact clearly contradicts the basic hypothesis of kinematical diffraction theory which states that the diffracted intensity is much lower than the transmitted beam intensity. Fig. 2c shows the dynamics of various Bragg peaks following photo-excitation at incident fluence of 12 mJ/cm<sup>2</sup>. In this case, the sample was oriented so that the (2-20) peak is slightly off Bragg. All Bragg peaks exhibit similar dynamics: the relative intensity  $\Delta I/I$  starts with a sharp decrease on the picosecond time scale. This is followed by a slower roll-off and further decrease on the 10 ps time scale. According to the above-mentioned scenario, the fast picosecond time scale can be attributed to electron relaxation and lattice heating via electron phonon coupling while the slower time scale can be attributed to delayed heating due to Auger recombination. After tens of picoseconds, the Bragg peak intensity is relatively flat and a quasi-steady state is established that lasts hundreds of picoseconds.

These different time scales are consistent with previous results [12], but a truly intriguing feature is the magnitude of the measured signal: the (2-20) peak decreases by 40% while the 0-order peak increases by nearly 30%. Even more surprisingly, we observed that the dynamics of the Bragg peak is extremely sensitive to sample orientation. In Fig. 3, we show the dynamics  $\Delta I/I(t)$  for the transmitted beam (a) and for the (2-20) peak (b) for five different sample orientations. The results are striking as

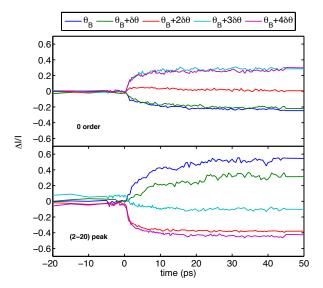


FIG. 3: Photo-induced dynamics for various sample orientations. The blue curve is obtained when the sample is exactly at the Bragg angle; the other curves are obtained by tilting the sample by  $\delta\theta=0.26^{\circ}$ . The incident fluence is  $12\,\mathrm{mJ/cm}^2$ . Top: dynamics of the transmitted beam. Bottom: dynamics of the (2-20) peak.

a 1° tilt can turn the intensity change of the (2-20) peak from -40% to almost 60%. Therefore, we not only observe a giant photo-induced response in the Bragg peak intensity but the sign of the response  $\Delta I/I$  is determined by sample orientation. It is also interesting to note that the 0-order and the (2-20) peak have a complementary behavior, indicating a possible coupling.

These observations are in complete contradiction with the predictions of kinematical theory. In kinematical theory, the 0-order should remain unchanged while the all (220) peaks should decrease by less than 10%. Finally, the magnitude of the intensity changes  $\Delta I/I$  should be independent on sample orientation.

In order to gain further insight on these large changes of intensity, we measured the rocking curves of several diffraction peaks. Figure 4 shows the rocking curve of the (2-20) peak at equilibrium (i.e. at 300 K, blue curves) and in the photo-excited state (red curves) taken 150 ps after the arrival of the pump pulse, i.e. after thermalization of the sample has occurred. Rocking curves are shown at two different electron energies. We plot the Bragg peak intensity I(s), where s is the amplitude of the deviation vector  $\mathbf{s} = \Delta \mathbf{k} - \mathbf{g}$ , and  $\mathbf{g}$  is the lattice reciprocal vector corresponding to the (2-20) peak. Figure 4 clearly shows that the shape and magnitude of the rocking curve changes upon photo-excitation. However, there is no angular shift of the rocking curve upon photo excitation, invalidating previous interpretations based on lattice expansion [13] or sample distortion [12]. In addition, the results of Fig. 4 summarize and clarify the surprising features of Fig. 3: for 45 keV electrons, the intensity change

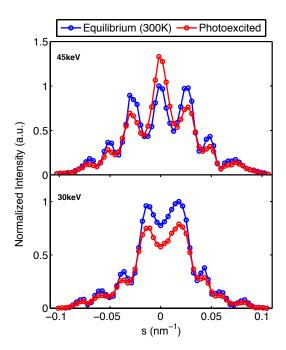


FIG. 4: Top: experimental rocking curves for the (2-20) peak taken with 45 keV electrons, at equilibrium  $T=300\,\mathrm{K}$  (blue curve) and in the photo-excited state (red curve), taken at  $t=150\,\mathrm{ps}$  delay. Bottom: same but using 30 keV electrons as a probe. The rocking curves were normalized relative to the equilibrium case.

is positive at the Bragg angle, whereas it is negative for most off-Bragg cases. For 30 keV electrons, the behavior is quite different: here, the intensity change is always negative after photo-excitation. The shape of these rocking curves, by departing from the usual  $\sin^2 x/x^2$  line shape of kinematical theory, indicates that dynamical effects are dominating the physics of electron diffraction, even at equilibrium.

#### IV. DISCUSSION

The fact that the rocking curve changes with temperature and electron energy can be understood quantitatively using a simplified version of dynamical diffraction theory: the 2-beam theory where one considers only the transmitted beam and one diffracted beam with intensity  $I_{\bf g}$ . In 2-beam theory, the diffracted intensity depends on the thickness of the sample L and reads

$$I_{\mathbf{g}}(s,L) = \frac{1}{V} \frac{\sin^2(s_e L/2)}{(s_e \xi_{\mathbf{g}})^2}$$
 (1)

where  $s_e = \sqrt{s^2 + 1/\xi_{\bf g}^2}$  is the amplitude of the effective deviation vector and  $\xi_{\bf g}$  is the extinction distance. The extinction distance defines the shape of the rocking curve and changes of  $\xi_{\bf g}$  will modify the rocking curve.

At T=0 K, the extinction distance reads  $\xi_{\mathbf{g}}=\frac{1}{\gamma\lambda}\frac{\pi\hbar^2}{m_eU_g}$  where  $m_e$  is the electron mass,  $\gamma=1+E/m_ec^2$  is the Lorentz factor of an electron with kinetic energy E. The two beams are coupled through  $U_{\mathbf{g}}$ , the Fourier component of the crystal potential  $V(\mathbf{r})$  corresponding to reciprocal lattice vector  $\mathbf{g}$ :  $V(\mathbf{r})=\sum_{\mathbf{g}}U_{\mathbf{g}}e^{i\mathbf{g}\cdot\mathbf{r}}$ . Clearly, the extinction distance depends on electron energy via  $\gamma\lambda$ , explaining why the rocking curve changes with electron energy. The temperature dependence can be accounted for by formally replacing  $U_{\mathbf{g}}$  by  $U_{\mathbf{g}}e^{-M}$  [27]. Consequently, the extinction distances with temperature [28] like  $\xi_{\mathbf{g}}(T)=\xi_{\mathbf{g}}(0)e^M$ . Evidently, a rise in temperature causes an increase of  $\xi_{\mathbf{g}}$ , implying changes of the shape of the rocking curve.

We found that 2-beam theory does not allow us to fit our experimental rocking curves and that additional Bragg peaks need to be taken into account. This is also apparent in the experimental data of Fig. 3: the diffracted intensity is not conserved if one considers only the 0-order and the (2-20) peak, indicating that more diffracted beams need to be considered. Therefore, we turned to a N-beam theory and solved the Howie-Whelan equations [29]

$$\frac{\partial \phi_{\mathbf{g}}}{\partial z} = i s_{\mathbf{g}} \phi_{\mathbf{g}} + \sum_{\mathbf{g}' \neq \mathbf{g}} \frac{i}{2\xi_{\mathbf{g} - \mathbf{g}'}} \phi_{\mathbf{g}'}$$
 (2)

Here,  $\phi_{\mathbf{g}}$  is the amplitude of the diffraction peak  $\mathbf{g}$  and two peaks  $\phi_{\mathbf{g}}$  and  $\phi_{\mathbf{g}'}$  are coupled through the extinction distance  $\xi_{{f g}-{f g}'} \propto 1/U_{{f g}-{f g}'}$ . Implementing this method requires the detailed knowledge of the scattering potential. Silicon data on the various  $U_{\mathbf{g}-\mathbf{g}'}$  was taken from the code JEMS [30]. In the experiment, we detect 12 diffraction peaks during a rocking curve scan but we found that the N-beam theory converges for N > 24 and we present results with N=26 (more details can be found in the appendix). Figure 5 a-b) shows the results of the calculations for  $E=45\,\mathrm{keV}$  electrons and  $30\,\mathrm{keV}$  electrons without considering absorption. The experimental trends are well reproduced: the shapes of the calculated rocking curves are similar to the experimental ones. In particular, the signs of the relative intensity change is reproduced:  $\Delta I(s=0)/I > 0$  at 45 keV and  $\Delta I(s=0)/I < 0$ at 30 keV. However, the experimental data in Fig.4 displays a large background and the diffracted intensity I(s)oscillates but never cancels to zero, in contradiction with dynamical diffraction calculations. Experimentally, the background can be due to many factors, such as inelastic scattering (on phonons, plasmons, defects...), surface contamination or surface amorphization. Because of the difficulty of modeling all these effects, we turn to a phenomenological approach and model the background using a simple gaussian distribution. We were able to obtain a quantitative fit of the experimental data using the following function:

$$I(s) = AI_{dyn} + Be^{-s^2/\sigma^2}$$

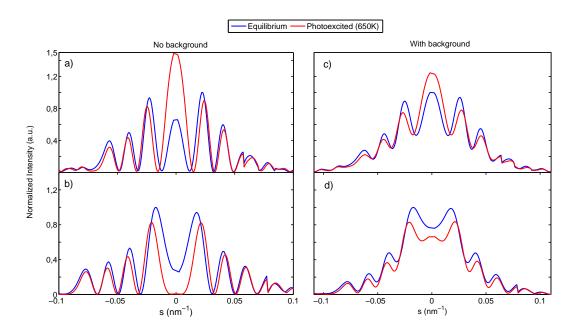


FIG. 5: Results of N-beam dynamical diffraction theory with N=26 beams: a) calculated rocking curves for the (2-20) peak in the case of 45 keV electrons. The blue curve shows the result at  $T=300\,\mathrm{K}$  and at  $T=650\,\mathrm{K}$  (red curve), b) same calculations but with 30 keV electrons. In figures c) and d), a gaussian background that was added to the N-beam calculations in order to better fit the data. The rocking curves are normalized relative to the equilibrium case.

where  $I_{dyn}$  is given by dynamical theory (no free parameters) and A, B and  $\sigma$  are free parameters allowing us to fit the experimental data more accurately. While N-beam theory reproduces all the trends of the experiment, the data can be even better fitted by adding this gaussian background to the results of the N-beam calculations as shown in Fig. 5 c) and d). The photo-excited state was best fitted considering a  $T=650\,\mathrm{K}$  temperature. Results are represented by the red curves in Fig. 5, showing excellent agreement with the measurements.

We conclude that the observed dynamics of the Bragg peaks and in particular the behavior of  $\Delta I/I$  can be fully explained by lattice heating and dynamical diffraction effects. In particular, we obtained the non-intuitive result that depending on the electron energy and the sample orientation, lattice heating can cause an increase of the Bragg peak intensity, contrary to the well-known Debye-Waller effect.

#### V. CONCLUSION

While this study was performed on silicon, we anticipate that such effects should be present in all materials provided that the crystal quality is high and the thickness comparable with the extinction distance. Indeed, when  $L \ll 2\pi \xi_{\bf g}$ , multiple scattering can be neglected and kinematic theory appears to be a valid approxima-

tion. Typical extinction distances are tens of nanometers  $(2\pi\xi_{220} = 56 \,\mathrm{nm} \,\mathrm{for \, silicon \, at \, 45 \, keV})$ , so that multiple scattering and dynamical effects have to be considered as soon as the sample thickness is larger than 1-10 nm, depending on the material. In conclusion, we have shown that multiple scattering effects play an important role when UED experiments are performed on high quality single crystals, consequently these effects should be always considered. Nonetheless, the quantitative interpretation of UED experiments might become quite complex as modeling multiple scattering requires prior knowledge of the crystal scattering potential. Dynamical effects, in turn, could potentially be used to obtain new information on the dynamics of the crystal potential. Finally, dynamical effects are also useful to visualize crystal defects, such as dislocation or stacking faults [15]. Therefore, they should enable a new type of experiments in which the dynamics of defects following laser irradiation can be studied using ultrafast electron imaging.

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# Appendix: N-BEAM DYNAMICAL DIFFRACTION THEORY

In dynamical theory, the main electron beam diffracts into N-1 diffracted beams because of its interaction with the crystal scattering potential. The crystal scattering potential is developed into a Fourier series as

$$V(\mathbf{r}) = \sum_{\mathbf{g}} U_{\mathbf{g}} e^{i\mathbf{g} \cdot \mathbf{r}} \tag{3}$$

where  $\mathbf{g}$  are the lattice reciprocal vectors, and  $U_{\mathbf{g}}$  are the potential Fourier components corresponding to  $\mathbf{g}$ . The scattered wave function is also written as a Fourier series:  $|\psi\rangle = \sum_{\mathbf{g}} \phi_{\mathbf{g}} |\mathbf{k} + \mathbf{g}\rangle$ , where  $\phi_{\mathbf{g}}$  are the amplitude of the scattered wave in diffraction peak corresponding to vector  $\mathbf{g}$ . Injecting these expressions into the Shrödinger equation and solving in Fourier space, one obtains the Howie-Whelan equations:

$$\frac{\partial \phi_{\mathbf{g}}}{\partial z} = i s_{\mathbf{g}} \phi_{\mathbf{g}} + \sum_{\mathbf{g}' \neq \mathbf{g}} \frac{i}{2\xi_{\mathbf{g} - \mathbf{g}'}} \phi_{\mathbf{g}'}$$
(4)

where  $s_{\bf g}$ , the deviation error, depends on the crystal orientation, and  $\xi_{{\bf g}-{\bf g}'}=\frac{1}{\lambda}\frac{2\hbar^2}{m_e U_g}$  is the extinction distance. The extinction distance is related to  $U_{{\bf g}-{\bf g}'}$  which causes a coupling of the two diffracted beams  $\phi_{\bf g}$  and  $\phi_{{\bf g}'}$  because  $\langle {\bf k}+{\bf g}|\hat{V}|{\bf k}+{\bf g}'\rangle=\langle {\bf k}+{\bf g}|U_{{\bf g}-{\bf g}'}e^{i({\bf g}-{\bf g}')}|{\bf k}+{\bf g}'\rangle\neq 0$ . Note that for a weakly relativistic electron, the effect of the relativistic mass increase can be included simply by replacing  $m_e$  by  $\gamma m_e$  where  $\gamma=1+E/m_ec^2$  is the electron Lorentz factor. The Howie-Whelan equations describe the evolution of the scattered wave intensities during propagation of the electron into the sample. This system of N coupled differential equations can be written in matrix form:

$$\frac{d\Phi}{dz} = iM\Phi\tag{5}$$

where  $\Phi$  is a column vector of length N and M is a  $N \times N$  matrix that can be decomposed as

$$M = \begin{pmatrix} 0 & 0 & 0 & \dots \\ 0 & s_{g_1} & 0 & \dots \\ 0 & 0 & s_{g_2} & \dots \\ \vdots & \vdots & & \ddots \end{pmatrix} + \Delta \begin{pmatrix} 0 & U_{-g_1} & U_{-g_2} & U_{-g_3} & \dots \\ U_{g_1} & 0 & U_{g_1 - g_2} & U_{g_1 - g_3} & \dots \\ U_{g_2} & U_{g_2 - g_1} & 0 & U_{g_2 - g_3} & \dots \\ \vdots & \vdots & & \ddots & \end{pmatrix}$$

with

$$\Delta = \frac{\gamma m_e}{2\pi\hbar^2} \lambda$$

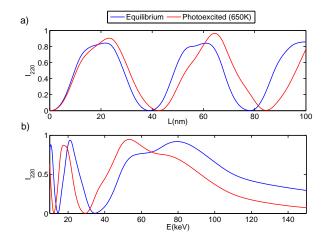


FIG. 6: Results of dynamical diffraction theory including N=26 beams. a) Intensity of the (220) peak at the Bragg angle,  $I_{220}(s=0)$  for varying sample thicknesses, assuming 45 keV electrons. b) Intensity of the (220) peak at the Bragg angle,  $I_{220}(s=0)$  for varying electron energy, assuming a 70 nm thickness.

The left matrix is diagonal and its elements are the amplitudes of the deviation vectors for each diffraction peak  $s_{\mathbf{g}-\mathbf{g}'}$ . The right matrix is composed of the Fourier amplitudes  $U_{\mathbf{g}-\mathbf{g}'}$ . This is an eigenvalue problem and the solution is found by diagonalizing matrix M. If D is the diagonal matrix in the basis of eigenvectors and C is the matrix for changing basis, we have  $M = CDC^{-1}$  and the solution of the problem is given by

$$\Phi(z) = Ce^{iDz}C^{-1}\Phi(0)$$

This general solution allows us to compute the amplitude of the various diffracted peaks  $\phi_{\mathbf{g}}(L)$  at the output of the crystal, z=L. This theory can be used provided that the crystal potential V(r) is precisely known. In our case, we extracted the  $U_{\mathbf{g}}$  matrix for the silicon potential from the code JEMS. We modeled the experiment assuming a 70 nm thickness and considering N=26 beams, including all (220), (400), (440), (620) peaks and a few higher order peaks as well. Such a high number of beams was necessary to ensure the convergence in the shape of the (220) rocking curve. Note that there are no free parameters in this model.

As a complement, we show in fig. 6 different non intuitive behaviors of dynamical diffraction effects. Figure 6a) shows the evolution of the (220) peak at the Bragg angle, s=0, as a function of thickness. The diffracted intensity oscillates along propagation in the sample which is one of the main feature of dynamical diffraction. Interestingly, the diffracted intensity in the high temperature case (red curve) shows a different behavior, indicating that the relative intensity changes are also expected to change sign depending on the sample thickness. Note that for small thicknesses, one recovers kinematical theory and  $\Delta I/I < 0$ , i.e. the diffracted intensity is smaller

in the high temperature case. Figure 6b) shows a similarly complex behavior when the electron energy is varied. This indicates that the relative intensity  $\Delta I/I$  have varying amplitude and sign depending on the energy of the probing electrons. We conclude that the ultrafast response of the Bragg peak intensity is, in general, greatly dependent on the sample thickness and the electron energy.

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